1



SAMTM Data Sheet SAM-1064-2-10ps-x, λ = 1064 nm

Laser wavelength $\lambda = 1064 \text{ nm}$

High reflection band $\lambda = 1010 ... 1090 \text{ nm}$

Absorbance $A_0 = 2 \%$ Modulation depth $\Delta R = 1.2 \%$ Non-saturable loss $A_{ns} = 0.8 \%$ Saturation fluence $\Phi_{sat} = 90 \ \mu \text{J/cm}^2$

Relaxation time constant $\tau \sim 10 \text{ ps}$

Damage threshold Φ = 3 mJ/cm²

Chip area 4.0 mm x 4.0 mm; other dimensions on request

Chip thickness 450 µm

Protection the SAM is protected with a dielectric front layer

Mounting option \mathbf{x} denotes the type of mounting as follows:

 $\mathbf{x} = 0$ unmounted $\mathbf{x} = 12.7 \, \mathrm{g}$ glued on a gold plated Cu-cylinder with 12.7 mm \varnothing $\mathbf{x} = 25.4 \, \mathrm{g}$ glued on a gold plated Cu-cylinder with 25.4 mm \varnothing $\mathbf{x} = 12.7 \, \mathrm{s}$ soldered on a gold plated Cu-cylinder with 12.7 mm \varnothing

x = 25.4 ssoldered on a gold plated Cu-cylinder with 25.4 mm \emptyset x = 25.4 wsoldered on a water cooled Cu-cylinder with 25.4 mm \emptyset x = FCmounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance

